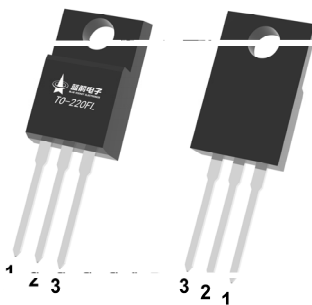
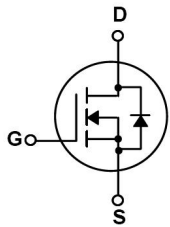


TO-220FL N MOS N-CHANNEL MOSFET in a TO-220FL Plastic Package.

Low gate charge, low crss, fast switching.

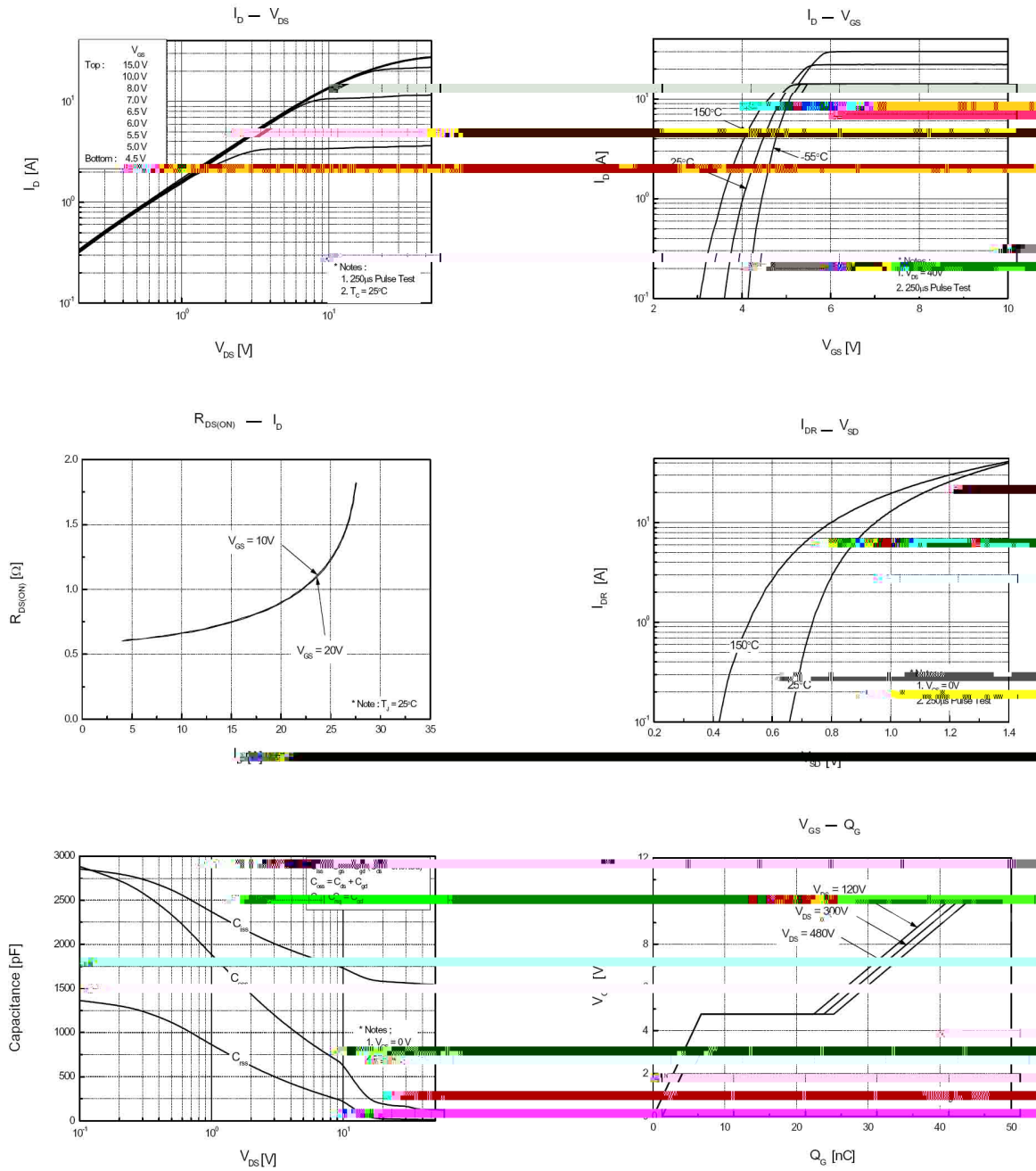
These devices are well suited for high efficiency switching DC/DC converters .

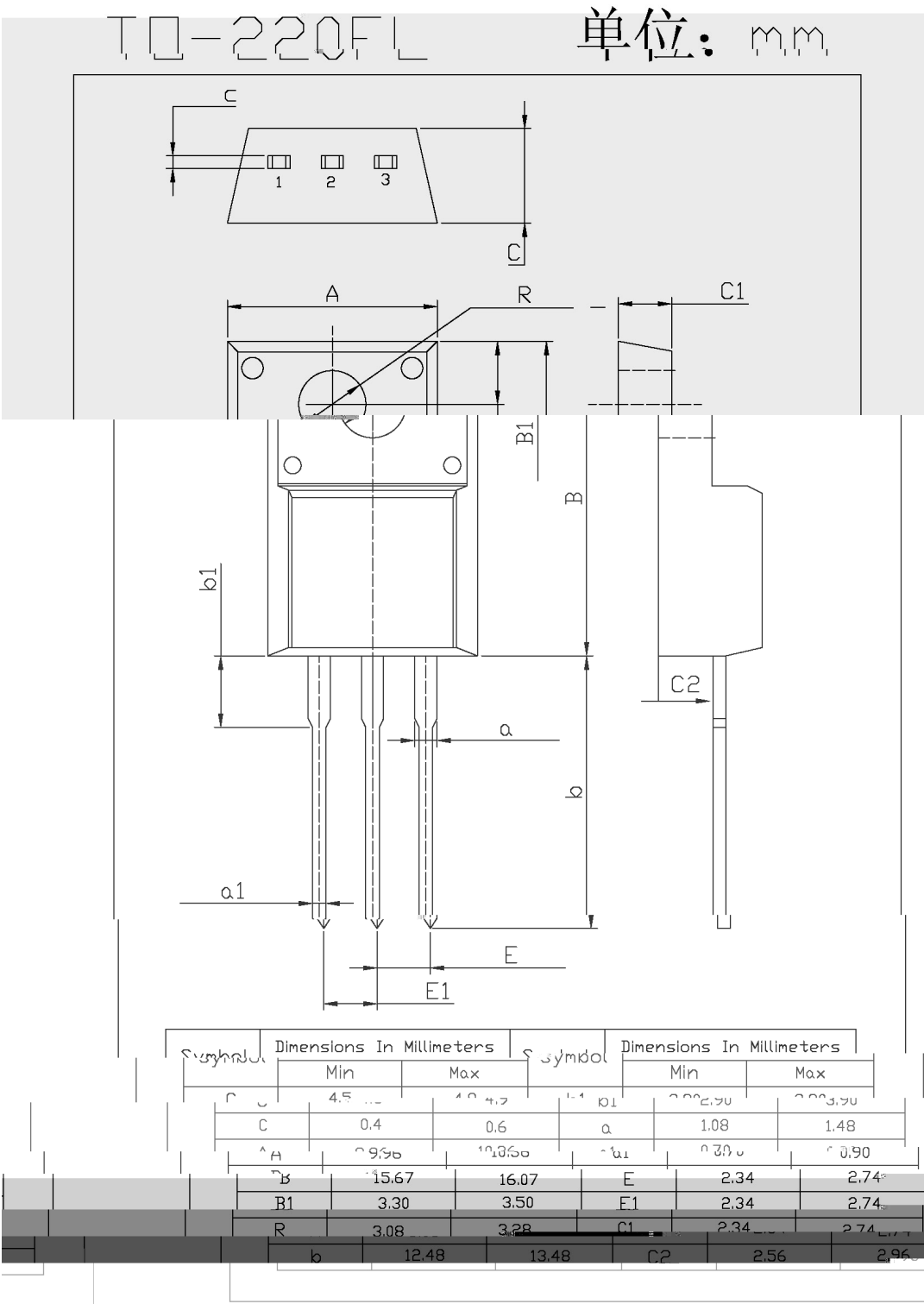


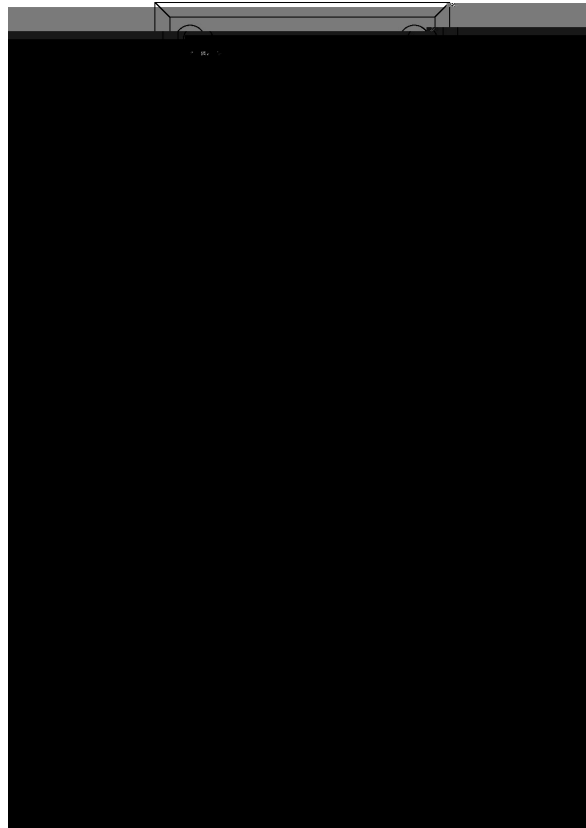
PIN1 G PIN 2 D PIN 3 S

See Marking Instructions.

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	600	V
Drain Current	$I_D(T_C=25^\circ\text{C})$	9.5	A
Drain Current	$I_D(T_C=100^\circ\text{C})$	5.7	A
Drain Current - Pulsed	I_{DM}	38	A
Gate-Source Voltage	V_{GS}	± 30	V
Single Pulsed Avalanche Energy	E_{AS}	700	mJ
Repetitive Avalanche Energy	E_{AR}	15.6	mJ
Avalanche Current	I_{AR}	9.5	A
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	/W
Power Dissipation	$P_D(T_C=25^\circ\text{C})$	50	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to 150	







BR

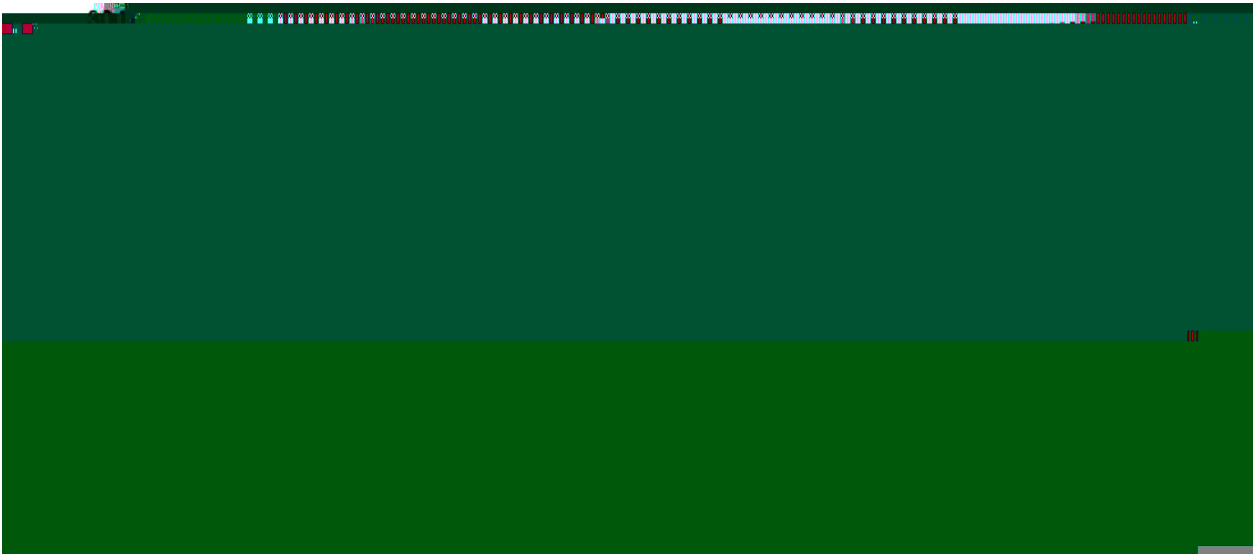
10N60

Note:

BR: Company Code

10N60: Product Type Code

***: Lot No. Code, code change with Lot No



- 1

25 150

60 90sec;

2

255 5

5 0.5sec;

3

2 10 /sec.
- Note:
1.Preheating:25~150 , Time:60~90sec.
2.Peak Temp.:255 5 , Duration:5 0.5sec.
3. Cooling Speed: 2~10 /sec.

270 5

10 1 sec.

Temp.:270±5

Time:10±1 sec

/ TUBE

Package Type	Units					Dimension (unit mm ³)		
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Tube	Inner Box	Outer Box
TO-220FL	50	20	1,000	5	5,000	532×33×7.0	555×164×50	575×290×180